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**ON Semiconductor**<sup>®</sup>

# FJP13007 High Voltage Fast-Switching NPN Power Transistor

#### Features

- High Voltage High Speed Power Switch Application
- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Switching Mode Power Supply



1.Base 2.Collector 3.Emitter

#### **Ordering Information**

| Part Number       | Top Mark | Package                  | Packing Method |
|-------------------|----------|--------------------------|----------------|
| FJP13007TU        | J13007   | TO-220 3L (Dual Gauge)   | Rail           |
| FJP13007H1TU      | J13007-1 | TO-220 3L (Single Gauge) | Rail           |
| FJP13007H1TU-F080 | J13007-1 | TO-220 3L (Dual Gauge)   | Rail           |
| FJP13007H2TU      | J13007-2 | TO-220 3L (Dual Gauge)   | Rail           |
| FJP13007H2TU-F080 | J13007-2 | TO-220 3L (Dual Gauge)   | Rail           |

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_c = 25^{\circ}C$  unless otherwise noted.

| Symbol           | Parameter                                     | Value      | Unit |
|------------------|---|------------|------|
| V <sub>CBO</sub> | Collector-Base Voltage                        | 700        | V    |
| V <sub>CEO</sub> | Collector-Emitter Voltage                     | 400        | V    |
| V <sub>EBO</sub> | Emitter-Base Voltage                          | 9          | V    |
| ۱ <sub>C</sub>   | Collector Current (DC)                        | 8          | Α    |
| I <sub>CP</sub>  | Collector Current (Pulse)                     | 16         | A    |
| I <sub>B</sub>   | Base Current (DC)                             | 4          | A    |
| P <sub>C</sub>   | Collector Dissipation ( $T_C = 25^{\circ}C$ ) | 80         | W    |
| ТJ               | Junction Temperature                          | 150        | °C   |
| T <sub>STG</sub> | Storage Temperature Range                     | -65 to 150 | °C   |

## **Electrical Characteristics**

Values are at  $T_C = 25^{\circ}C$  unless otherwise noted.

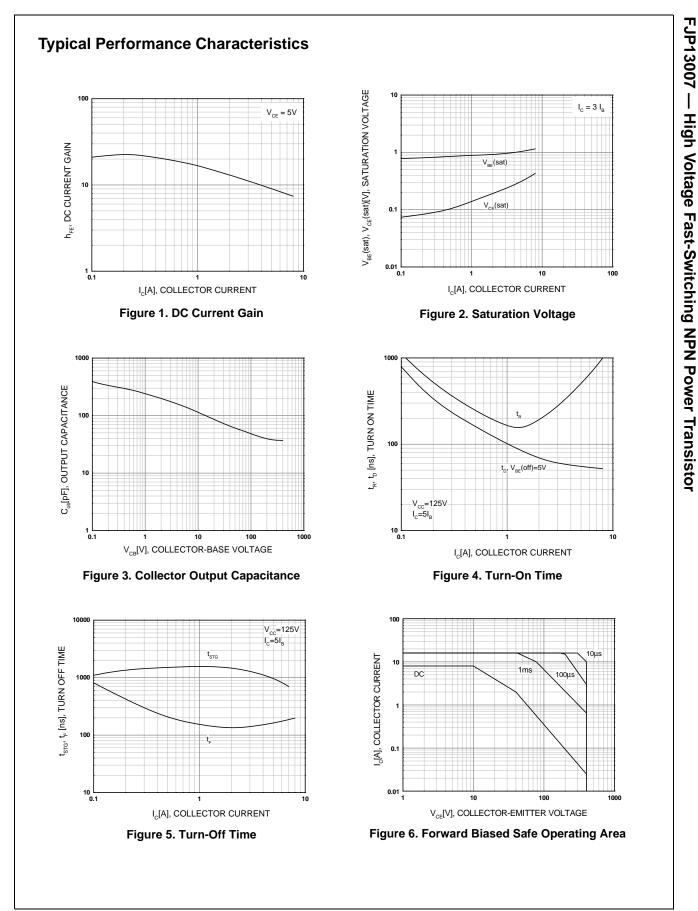
| Symbol                | Parameter                            | Conditions   | Min. | Тур. | Max. | Unit |
|-----------------------|--------------------------------------|--|------|------|------|------|
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0             | 400  |      |      | V    |
| I <sub>EBO</sub>      | Emitter Cut-Off Current              | $V_{EB} = 9 V, I_{C} = 0$                              |      |      | 1    | mA   |
| h <sub>FE</sub> 1     | DC Current Gain <sup>(1)</sup>       | $V_{CE} = 5 V, I_{C} = 2 A$                            | 8    |      | 60   |      |
| h <sub>FE</sub> 2     | DC Current Gain <sup>(1)</sup>       | $V_{CE} = 5 V, I_{C} = 5 A$                            | 5    |      | 30   |      |
| V <sub>CE</sub> (sat) |                                      | I <sub>C</sub> = 2 A, I <sub>B</sub> = 0.4 A           |      |      | 1.0  | V    |
|                       | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 5 A, I <sub>B</sub> = 1 A             |      |      | 2.0  |      |
|                       |                                      | I <sub>C</sub> = 8 A, I <sub>B</sub> = 2 A             |      |      | 3.0  |      |
| )/ (aat)              | Collector Pass Saturation Voltage    | $I_{\rm C} = 2 \text{ A}, I_{\rm B} = 0.4 \text{ A}$   |      |      | 1.2  | V    |
| V <sub>BE</sub> (sat) | Collector-Base Saturation Voltage    | I <sub>C</sub> = 5 A, I <sub>B</sub> = 1 A             |      |      | 1.6  |      |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | $V_{CE} = 10 \text{ V}, \text{ I}_{C} = 0.5 \text{ A}$ | 4    |      |      | MHz  |
| C <sub>ob</sub>       | Output Capacitance                   | V <sub>CB</sub> = 10 V, f = 0.1 MHz                    |      | 110  |      | pF   |
| t <sub>ON</sub>       | Turn-On Time                         | V <sub>CC</sub> = 125 V, I <sub>C</sub> = 5 A,         |      |      | 1.6  | μs   |
| t <sub>STG</sub>      | Storage Time                         | I <sub>B1</sub> = -I <sub>B2</sub> = 1 A,              |      |      | 3.0  | μs   |
| t <sub>F</sub>        | Fall Time                            | $R_L = 25 \Omega$                                      |      |      | 0.7  | μs   |

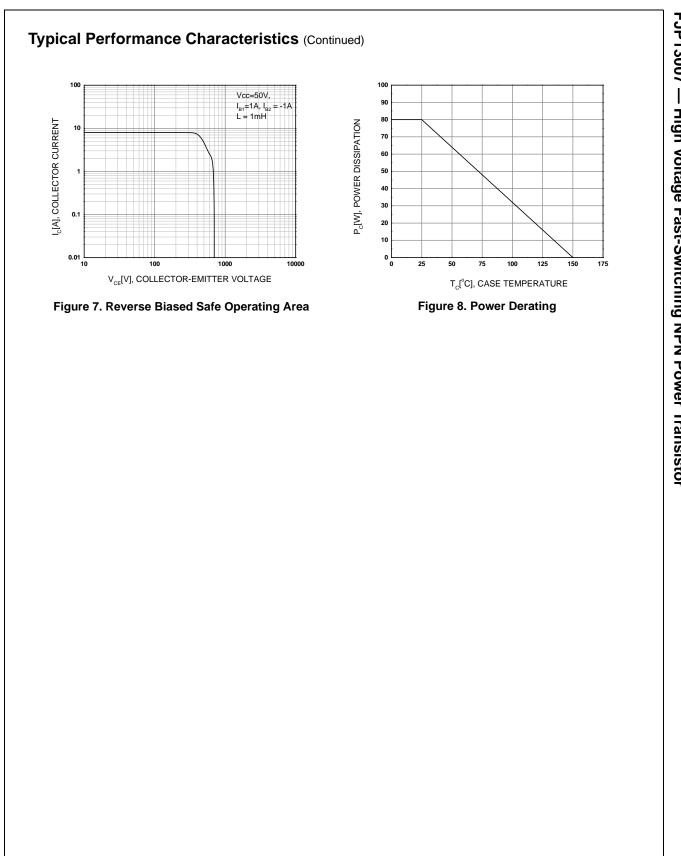
#### Note:

1. Pulse test:  $pw \le 300 \ \mu s$ , duty cycle  $\le 2\%$ .

## h<sub>FE</sub> Classification

| Classification    | H1      | H2      |
|-------------------|---------|---------|
| h <sub>FE</sub> 1 | 15 ~ 28 | 26 ~ 39 |





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